Unbuffered Inverter

The MC74VHC1GU04 is an advanced high speed CMOS Unbuffered inverter fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This device consists of a single unbuffered inverter. In combination with others, or in the MC74VHCU04 Hex Unbuffered Inverter, these devices are well suited for use as oscillators, pulse shapers, and in many other applications requiring a high–input impedance amplifier. For digital applications, the MC74VHC1G04 or the MC74VHC04 are recommended.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output.

The MC74VHC1GU04 input structure provides protection when voltages up to 7V are applied, regardless of the supply voltage. This allows the MC74VHC1GU04 to be used to interface 5V circuits to 3V circuits.

- High Speed: $t_{PD} = 2.5 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2\mu A$ (Max) at $T_A = 25^{\circ}C$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300mA

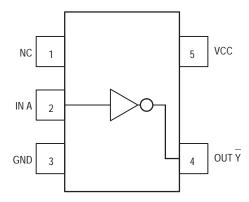


Figure 1. 5-Lead SOT-353 Pinout (Top View)





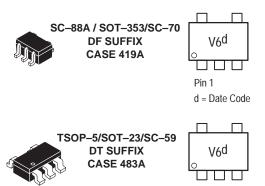
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MARKING DIAGRAMS

Pin 1

d = Date Code



PIN ASSIGNMENT1NC2IN A3GND4OUT Y5VCC

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

FUNCTION TABLE

A Input	Y Output
L	Н
Н	L
н	L

MAXIMUM RATINGS*

Characteristics	Symbol	Value	Unit
DC Supply Voltage	Vcc	-0.5 to +7.0	V
DC Input Voltage	VIN	-0.5 to +7.0	V
DC Output Voltage V _{CC} = 0 High or Low State	Vout	-0.5 to 7.0 -0.5 to V _{CC} + 0.5	V
Input Diode Current	Iк	-20	mA
$\label{eq:VOUT} \text{Output Diode Current} \qquad (\text{V}_{\text{OUT}} < \text{GND}; \text{V}_{\text{OUT}} > \text{V}_{\text{CC}})$	IOK	+20	mA
DC Output Current, per Pin	IOUT	+25	mA
DC Supply Current, V_{CC} and GND	ICC	+50	mA
Power dissipation in still air, SC-88A †	PD	200	mW
Lead temperature, 1 mm from case for 10 s	ΤL	260	°C
Storage temperature	T _{stg}	-65 to +150	°C

* Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — SC-88A Package: -5 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Characteristics	Symbol	Min	Max	Unit
DC Supply Voltage	VCC	2.0	5.5	V
DC Input Voltage	VIN	0.0	5.5	V
DC Output Voltage	VOUT	0.0	VCC	V
Operating Temperature Range	TA	-55	+125	°C
Input Rise and Fall Time $$V_{CC}$=3.3V\pm0.3V$\\ V_{CC}=5.0V\pm0.5V$$	t _r , t _f	0 0	No Limit No Limit	ns/V

The θ_{JA} of the package is equal to 1/Derating. Higher junction temperatures may affect the expected lifetime of the device per the table and figure below.

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

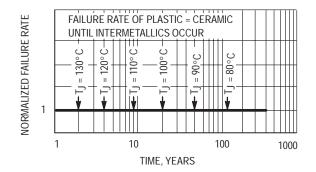


Figure 2. Failure Rate vs. Time Junction Temperature

			Vcc	т	A = 25°0	C	T _A ≤	85°C	TA ≤ '	125°C	
Symbol	Parameter	Test Conditions	(V)	Min	Тур	Мах	Min	Max	Min	Max	Unit
VIH	Minimum High–Level Input Voltage		2.0 3.0 4.5 5.5	1.7 2.4 3.6 4.4			1.7 2.4 3.6 4.4		1.7 2.4 3.6 4.4		V
VIL	Maximum Low–Level Input Voltage		2.0 3.0 4.5 5.5			0.3 0.6 0.9 1.1		0.3 0.6 0.9 1.1		0.3 0.6 0.9 1.1	V
V _{OH}	Minimum High–Level Output Voltage V _{IN} = V _{IH} or V _{IL}	VIN = VIH or VIL IOH = -50µA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		V
V _{OL}	Maximum Low–Level Output Voltage VIN = VIH or VIL	VIN = VIH or VIL IOL = 50µA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	V
I _{IN}	Maximum Input Leakage Current	$V_{IN} = 5.5V \text{ or GND}$	0 to 5.5			±0.1		±1.0		±1.0	μA
ICC	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			2.0		20		40	μA

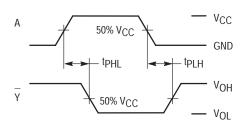
DC ELECTRICAL CHARACTERISTICS

AC ELECTRICAL CHARACTERISTICS ($C_{load} = 50 \text{ pF}$, Input $t_r = t_f = 3.0 \text{ns}$)

				T	A = 25°	C	T _A ≤	85°C	TA ≤ <i>'</i>	125°C	
Symbol	Parameter	Test Condi	tions	Min	Тур	Max	Min	Max	Min	Max	Unit
^t PLH [,] ^t PHL	Maximum Propogati <u>on</u> Delay,	$V_{CC} = 3.0 \pm 0.3 V$	C _L = 15 pF C _L = 50 pF		3.5 4.8	8.9 11.4		10.5 13.0		12.0 15.5	ns
	Input A to Y	$V_{CC} = 5.0 \pm 0.5 V$	C _L = 15 pF C _L = 50 pF		2.5 3.8	5.5 7.0		6.5 8.0		8.0 9.5	
C _{IN}	Maximum Input Capacitance				4	10		10		10	pF
						Ту	/pical @	25°C, V	CC = 5.0	DV	
Срр	Power Dissipation Car	pacitance (Note 1.)						22			рF

 CPD
 Power Dissipation Capacitance (Note 1.)
 22
 pF

 1. CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: ICC(OPR)=CPD • VCC • fin+ICC. CPD is used to determine the no-load dynamic power consumption; PD = CPD • VCC² • fin + ICC • VCC.



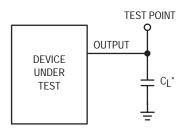


Figure 3. Switching Waveforms

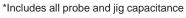
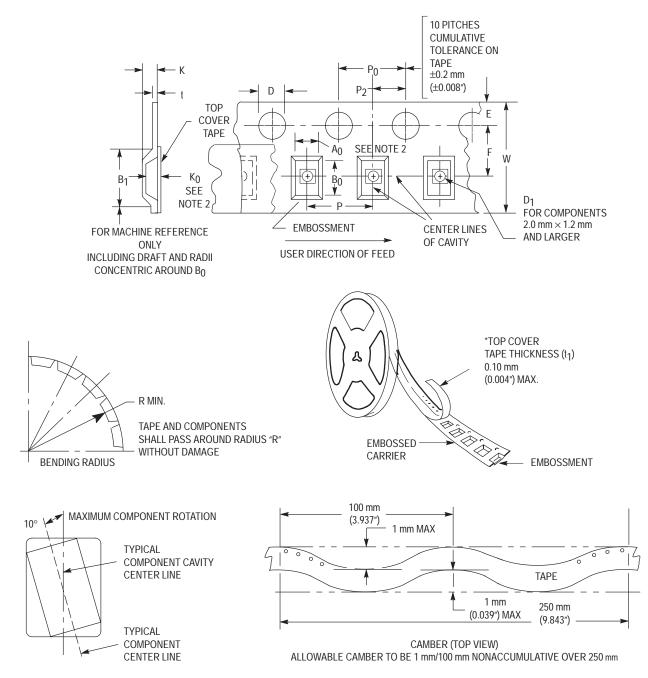


Figure 4. Test Circuit

DEVICE ORDERING INFORMATION

			Device Nome	enclature				
Device Order Number	Circuit Indicator	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type (Name/SOT#/ Common Name)	Tape and Reel Size
MC74VHC1GU04DFT1	MC	74	VHC1G	U04	DF	T1	SC-88A / SOT-353 / SC-70	178 mm (7") 3000 Unit
MC74VHC1GU04DFT2	MC	74	VHC1G	U04	DF	T2	SC-88A / SOT-353 / SC-70	178 mm (7") 3000 Unit
MC74VHC1GU04DFR2	MC	74	VHC1G	U04	DF	R2	SC-88A / SOT-353 / SC-70	330 mm (13") 10000 Unit
MC74VHC1GU04DTT2	MC	74	VHC1G	U04	DT	T2	TSOPS / SOT-23 / SC-59	178 mm (7") 3000 Unit
MC74VHC1GU04DTR2	MC	74	VHC1G	U04	DT	R2	TSOPS / SOT-23 / SC-59	330 mm (13") 10000 Unit





•					0 110100 1	ana _)				-		
Tape Size	B ₁ Max	D	D ₁	E	F	к	Р	P ₀	P ₂	R	т	w
8 mm	4.35 mm (0.171″)	1.5 +0.1/ -0.0 mm (0.059 +0.004/ -0.0")	1.0 mm Min (0.039")	1.75 ±0.1 mm (0.069 ±0.004")	3.5 ±0.5 mm (1.38 ±0.002")	2.4 mm (0.094")	4.0 ±0.10 mm (0.157 ±0.004")	4.0 ±0.1 mm (0.156 ±0.004")	2.0 ±0.1 mm (0.079 ±0.002")	25 mm (0.98")	0.3 ±0.05 mm (0.01 +0.0038/ -0.0002")	8.0 ±0.3 mm (0.315 ±0.012")

EMBOSSED CARRIER DIMENSION	S (See	Notes	1	and 2
EWIBOSSED CARRIER DIWIENSION	3 (366	110162		and z

1. Metric Dimensions Govern-English are in parentheses for reference only.

 A₀, B₀, and K₀ are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

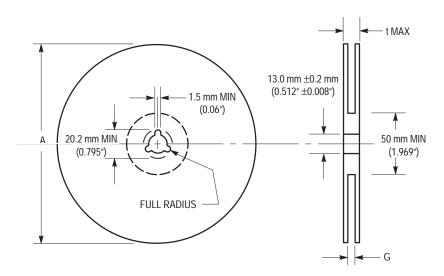
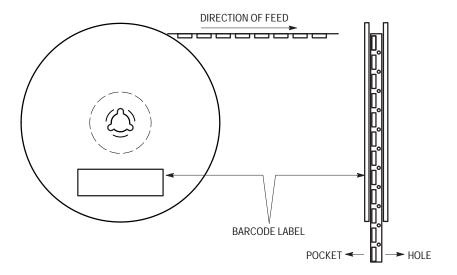


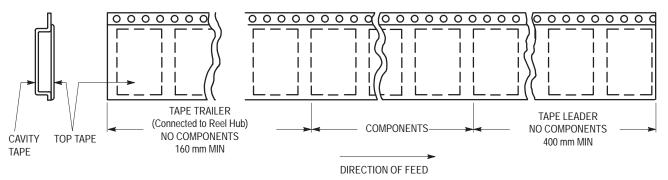
Figure 6. Reel Dimensions

REEL DIMENSIONS

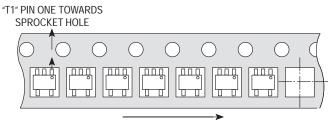
Tape Size	T&R Suffic	A Max	G	t Max
8 mm	T1, T2	178 mm (7″)	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56″)
8 mm	R2	330 mm (13")	8.4 mm, +1.5 mm, -0.0 (0.33" + 0.059", -0.00)	14.4 mm (0.56″)











User Direction of Feed

Figure 9. T1 Reel Configuration

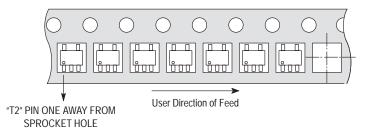
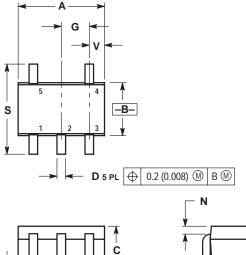


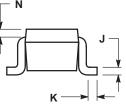
Figure 10. T2 Reel Configuration

SC-88A / SOT-353 / SC-70 **DF SUFFIX** 5-LEAD PACKAGE CASE 419A-01 ISSUE B



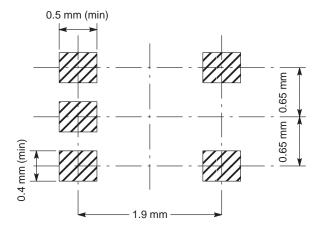
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NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MM.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.071	0.087	1.80	2.20		
В	0.045	0.053	1.15	1.35		
С	0.031	0.043	0.80	1.10		
D	0.004	0.012	0.10	0.30		
G	0.026	BSC	0.65 BSC			
Н		0.004		0.10		
J	0.004	0.010	0.10	0.25		
К	0.004	0.012	0.10	0.30		
Ν	0.008 REF		0.20	REF		
S	0.079	0.087	2.00	2.20		
٧	0.012	0.016	0.30	0.40		



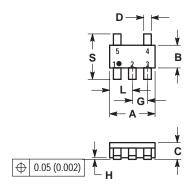
TSOP-5 / SOT-23 / SC-59 DT SUFFIX 5-LEAD PACKAGE CASE 483-01 **ISSUE A**

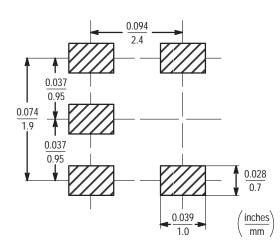
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NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.1142	0.1220	
В	1.30	1.70	0.0512	0.0669	
С	0.90	1.10	0.0354	0.0433	
D	0.25	0.50	0.0098	0.0197	
G	0.85	1.00	0.0335	0.0413	
Н	0.013	0.100	0.0005	0.0040	
J	0.10	0.26	0.0040	0.0102	
К	0.20	0.60	0.0079	0.0236	
L	1.25	1.55	0.0493	0.0610	
Μ	0 °	10 °	0°	10°	
S	2.50	3.00	0.0985	0.1181	





Notes

Notes

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